## Voltage Controlled Crystal Oscillator

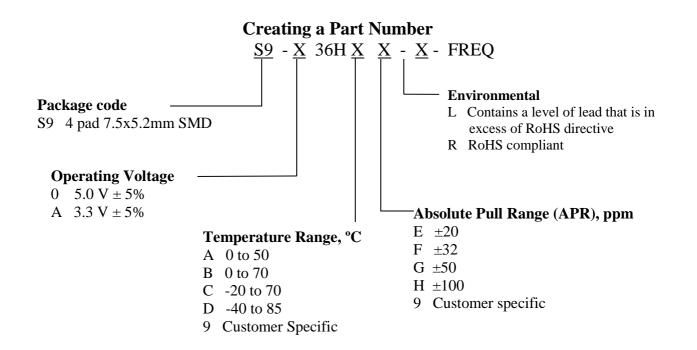
### S9-X36HXX-X Series **CMOS VCXO**

#### **Description**

The S9-X36HXX Series of voltage controlled crystal oscillators (VCXO) provides low phase noise CMOS output. The device packaged in a miniature, low profile, leadless FR-4 based package with gold plated pads, which enhances compatibility with PCB material.

### **Applications and Features**

- Low Phase Noise
- Wimax, Fiber Channel; 10 GbE; Infiniband; Network Processors; SOHO Routing
- High Reliability NEL HALT/HASS qualified for crystal oscillator start-up conditions
- Low cost
- COTS/Dual use





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Rev. H

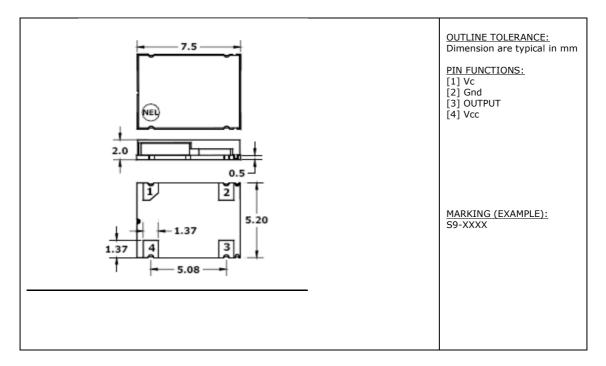
# Voltage Controlled Crystal Oscillator

### Data Sheet 0717A

### S9-X36HXX-X Series

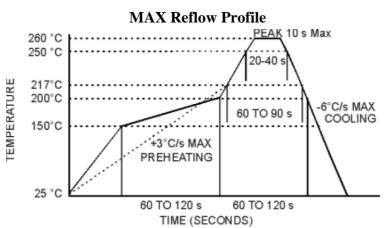
Rev. H





#### **Environmental and Mechanical Characteristics**

Operating temp.	see part # table	
Range	-	
Mechanical Shock	Per MIL-STD-202, Method 213, Cond. A	
Thermal Shock	Per MIL-STD-883, Method 1011, Cond. A	
Vibration	Per MIL-STD-883, Method 2007, Cond. A	
Hermetic Seal	Leak rate less than $1 \times 10^{-8}$ atm.cc/s of helium, crystal only.	
Soldering conditions	g conditions See MAX reflow profile below; The device may be reflowed once. Reflowing upside down is not	
	allowed. NO CLEAN assembly is recommended.	



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### S9-X36HXX-X Series

Rev. H

			Absol	ute Maxin	num Rating	gs		
Parameter				Symbol Value				Unit
Operating Temperature Range			То		-40 to +85			°C
Storage Temperature Range			Tst	Tst -50 to +90				°C
Supply Voltage			Vcc	Vcc		-0.5 to 5.5		V
Control Voltage				Vc		-0.5 to 5.5		
		1		trical Para	meters (2)		1	1
Parameter		Symb	Conditions, Note		MIN	TYP	MAX	Unit
Nominal Frequency		Fo			1		220	MHz
Supply Voltage		Vcc	Code 0 Code A		4.75 3.135	5.0 3.3	5.25 3.465	V
Supply current		Icc	@155 MHz, 3.3V			40	60	mA
Output Logic Type						CMOS		
Load						15 pF/10 KOhm		Ohm
Output Levels		Voh Vol	overall		0.9Vcc		0.1 Vcc	V
Duty Cycle	e (Symmetry)	101	At 50% Vcc		45/55	50/50	55/45	%
Rise/Fall Time		Tr/Tf	0.2Vcc to 0.8 Vcc; F< 70 MHz 70 MHz <f< 125="" mhz<br="">125MHz<f<220 mhz<="" td=""><td></td><td>3 2 1.5</td><td>5 3 2.5</td><td>ns</td></f<220></f<>			3 2 1.5	5 3 2.5	ns
Jitter	Integrated		Integrated from Phase Noise, 12 KHz to 20 MHz , RMS			0.1	0.2	ps
			100Hz to 801	KHz,RMS			1.0	ps
			50 KHz to 80 MHz			0.3		ps
	Wavecrest characterized		Random period,			2.5		ps
			Accumul., pk-to-pk			17		ps
			Determin.	F>52 MHz		6		ps
Sub-harmonics			F > 52 MHz			-50	-42	dBc
Phase Noise (1)		£( $\Delta f$ )	155.52 MHz,	@ 10 Hz @100 Hz @1 KHz @10KHz @100KHz @>1MHz		-70 -100 -125 -140 -145 -145		dBc/Hz
Frequency Stability, usually not specified – unless necessary, APR is specified to incorporate stability		ΔF/F	Overall, including temperature, aging 10 years, shock and vibration @Vc=Vcc/2; APR 50 ppm, or less		±20	±30		ppm
Control Voltage Range		Vc			0V		Vcc	V
Setability		Vcs	Vc to set the F at Fo; T, Vcc, load – nominal, as shipped		0.4 Vcc	0.5 Vcc	0.6 Vcc	V
Absolute Pull Range		APR	# creation	Over all conditions, see part				ppm
Input impedance		Zin	@ Fmod < 10	@ Fmod < 100 KHz				KOhm
Modulation Bandwidth			At $Vc = Vcc/2$ , -3dB		20			KHz

Abash-4. Marine Dating

Footnote: 1) If phase noise data at a particular frequency is needed, contact factory.

2) All parameters, unless otherwise specified, are at nominal conditions, ie: T=25°C, Nominal Vcc & Nominal Load.

